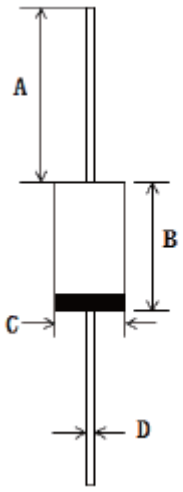
WS3B002500V

Silicon Carbide Schottky Diode

V_{RRM}	=	5000	V
I_F (T_C 75)	=	2	A
I_{FSM}	=	60	A

Features

Electrical Characteristics



1) Before using our products, please contact our marketing managers and get the latest specifications.

2) Ongoing efforts are being made to improve the reliability and quality of the products by CETC, but the semiconductors can malfunction due to various factors.